International

Data Sheet No. PD10041A

Series PVI5013R

Photovoltaic Isolator Solid-State Opto-Isolated MOSFET Gate Driver Dual-Channel, 5V, 1.0μA

General Description

The PVI5013R Photovoltaic Isolator is a dual-channel, opto-isolated driver capable of directly driving gates of power MOSFETs or IGBTs. It utilizes a monolithic integrated circuit photovoltaic generator of novel construction as its output. The output is controlled by radiation from a GaAlAs light emitting diode (LED) which is optically isolated from the photovoltaic generator.

The PVI5013R is ideally suited for applications requiring high-current and/or high voltage switching with optical isolation between the low-level driving circuitry and high-energy or high- voltage load circuits. It can be used for directly driving gates of power MOSFETs. The dual- channel configuration allows its outputs to drive independent discrete power MOSFETs, or be connected in parallel or in series to provide higher-current drive for power MOSFETs or higher-voltage drive for IGBTs. PVI5013R employs a fast turn-off circuitry.

PVI5013R Photovoltaic Isolators are packaged in an 8-pin, molded DIP package with either through-hole or surface-mount (gull-wing) terminals. It is available in standard plastic shipping tubes or on tape-andreel. Please refer to Part Identification information opposite.

Applications

- Telecommunications
- Load Distribution
- Industrial Controls
- Instrumentation and Measurement

Features

- Monolithic construction
- 3,750 V_{RMS} I/O isolation ■
- 1,200 V_{DC} output-to-output isolation ■
- Dual-Channel application flexibility
 - Solid-State reliability
 - BABT Certified



Part Identification

PVI5013R	through-hole
PVI5013RS	surface-mount
PVI5013RS-T	surface-mount, Tape and Reel

Series PVI5013R

International **IOR** Rectifier

Electrical Specifications (-40°C \leq T_A \leq +85°C unless otherwise specified)

Limits	Units
5.0	mA
3.0 to 25	mA
40	mA
1.4	V
7.0	V
10	μA
	Limits 5.0 3.0 to 25 40 1.4 7.0 10

OUTPUT CHARACTERISTICS	Limits	Units
Minimum Forward Voltage	8.0	V _{DC}
Maximum Reverse Current	10	μΑ _{DC}

COUPLED CHARACTERISTICS	Limits	Units
Minimum Output Voltage @ I_{LED} = 5mA, R_L = 10M Ω	3	V
@ T _A =0°C to +70°C (see figures 1 and 2)		
Maximum Output Voltage @ $I_{LED} = 5 \text{mA}, R_L = 10 \text{M}\Omega$	8	V
@ T _A =0°C to +70°C (see figures 1 and 2)		
Maximum Voltage Differential Between Outputs	1.0	V
$@$ I _{LED} = 5mA, R _L = 10M Ω		
Typical Output Short-Circuit Current	1.0	μA
@ I _{LED} = 5mA, @ T _A =+25°C (see figures 1 and 2)		
Maximum Turn-On Time @ I _{LED} = 5mA, C _{LOAD} = 200pF (see figure 4)	5	ms
Max. Turn-Off Time @ I _{LED} = 5mA, C _{LOAD} = 200pF (see figure 4)	0.25	ms
Off-State Clamping Resistance: minimum	100	Ω
maximum	3300	Ω

GENERAL CHARACTERISTICS		Limits	Units
Minimum Dielectric Strength, Input-Output		3750	V _{RMS}
Minimum Dielectric Strength, Output-to-Output		1200	V _{DC}
Vinimum Insulation Resistance, Input-to-Output 10 ¹²		0	
@T _A =+25°C, 50%RH, 100V _{DC}			
Maximum Capacitance, Input-Output		5.0	pF
Maximum Pin Soldering Temperature (10 seconds maximum)		+260	0°
Ambient Temperature Range:	Operating	-40 to +85	0°
	Storage	-40 to +125	°C

Connection Diagram



Series PVI5013R

International **TOR** Rectifier



Series PVI5013R

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